

THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:
BARR, ALEXANDER L. et al.

Application No.: 10/780143

Filed: 02-17-2004

Title: SEMICONDUCTOR STRUCTURE HAVING STRAINED SEMICONDUCTOR AND
METHOD THEREFOR

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Patent No.: 7205210 B2

Issue Date: 4/17/2007

Examiner: COLEMAN, W. DAVID

Group Art Unit: 2823

Docket No.: SC13265TP

Certificate of Submission

I hereby certify that this correspondence is being submitted to the
USPTO, Alexandria, VA.

- ☐ Addressed per C.F.R. § 1.1(a) and deposited with the United States
Postal Service with sufficient postage as first class mail.
- ☐ Facsimile transmitted in accordance with C.F.R. § 1.6(d).
- ☒ Submitted electronically via EFS in accordance with "Legal
Framework for EFS Web".

Date of Submission

Signature

Pat Thomas

Printed Name of Person Signing Certificate

Commissioner for Patents
Alexandria, VA 22313

SUBMISSION OF CERTIFICATE OF CORRECTION

Dear Commissioner:

Enclosed is a Certificate of Correction listing error(s) in the subject patent.
Please enter these corrections. Since some the errors appear to be on the part of the
Applicant, the appropriate fee will be paid electronically concurrently with this
submission.

Sept 21, 2007
Date

Respectfully submitted,

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CERTIFICATE OF CORRECTION**Page 1 of 1

PATENT NO.: 7205210 B2
APPLICATION NO: 10/780143
DATE: 02-17-2004
INVENTOR(S): BARR, ALEXANDER L. et al.

It is certified that error appears in the above-identified patent and that said Letters Patent are hereby corrected as shown below:

In Column 5, Line 45, Claim No. 3:

Change "form" to - -from- -

In Column 6, Line 3, Claim No.8:

Change "Method" to - -A method- -

In Column 6, Line 25, Claim No.9:

Change "Method" to - -A method- -

In Column 6, Line 51, Claim No.12:

Delete "a" after defining.

MAILING ADDRESS OF SENDER (Please do not use customer number below)

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